

#### Over-voltage Protection Thyristor

#### Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

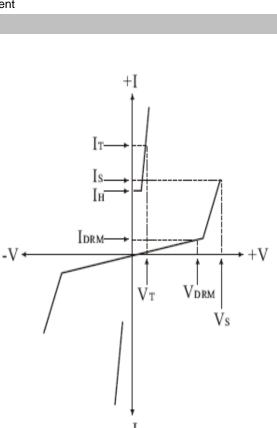
Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- · Have low capacitance, making them ideal for high-speed transmission equipment

#### **Electrical Parameters**

Parameter	Definition	
<b>C</b> 0	<b>Off-state Capacitance</b> — typical capacitance measured in off state	
di/dt	<b>Rate of Rise of Current</b> — maximum rated value of the acceptable rate of rise in current over time	
Is	<b>Switching Current</b> — maximum current required to switch to on state	
<b>I</b> DRM	<b>Leakage Current</b> — maximum peak off-state current measured at VDRM	
$\mathbf{I}^{ ext{H}}$	Holding Current — minimum current required to maintain on state	_
$\mathbf{I}$ PP	<b>Peak Pulse Current</b> — maximum rated peak impulse current	-V ←
IT	<b>On-state Current</b> — maximum rated continuous on-state current	$\int$
<b>I</b> TSM	<b>Peak One-cycle Surge Current</b> — maximum rated one-cycle AC current	/
<b>V</b> S	<b>Switching Voltage</b> — maximum voltage prior to switching to on state	,
<b>V</b> DRM	<b>Peak Off-state Voltage</b> — maximum voltage that can be applied while maintaining off state	
VF	<b>On-state Forward Voltage</b> — maximum forward voltage measured at rated on-state current	
ν	<b>On-state Voltage</b> — maximum voltage measured at rated on-state current	

1





SP3500SA

ROHS

# Senchip

#### **P** Series

er-voltage	Protection	Thyristor		SP	3500SA			ROH
ctricalCha	racterist	ics						
Part	Vdrm	Vs	VT	Idrm	Is	Іт	Ін	Co
Number*	Volts	Volts	Volts	µ Amps	mAmps	Amps	mAmps	pF
SP3500SA	320	400	4	5	800	2.2	150	30

\* For surge ratings, see table below.

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

• Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Rat:	ings						
Series	Ipp 2/10 μs Amps	Ipp 8/20 μs Amps	Ipp 10/160 μs Amps	IPP 10/560 μs Amps	IPP 10/1000 µs Amps	Ітым 60 Hz Amps	di/dt Amps∕µs
A	150	150	90	50	45	20	500
Thermal Co	onsiderations						
Package	DO-214AA/SMB	Symbol		Parameter		Value	Unit
		$T_{\rm J}$	Operatin	g Junction Ten	nperature	-40 to +150	°C
		Ts	Storage	e Temperature	Range	-40 to +150	$^{\circ}\mathrm{C}$
		R o JA	unction to	Ambient on p	rinted circuit	120	°C/W



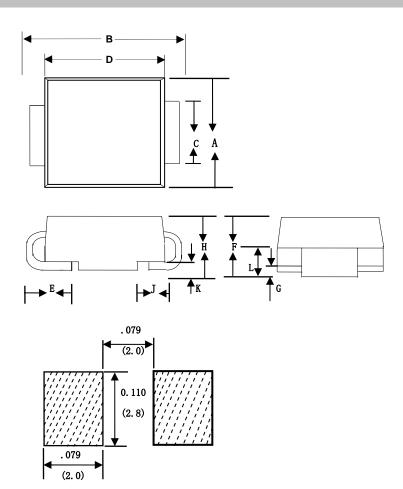
## Over-voltage Protection Thyristor

## **P** Series

ROHS

## SP3500SA

#### Dimensions



C	M	D
S	IVI.	D

Dimension	In	ches	Millimeters		
Dimension	MIN MAX		MIN	MAX	
А	0. 134	0. 155	3. 40	3.94	
В	0. 205	0. 22	5. 21	5. 59	
С	0.075	0. 083	1. 90	2. 11	
D	0. 166	0. 185	4. 22	4. 70	
Е	0. 036	0.056	0. 91	1.42	
F	0.073	0. 087	1.85	2.2	
G	0.002	0.008	0. 05	0. 20	
Н	0.077	0.094	1.95	2.40	
J	0. 043	0. 053	1.09	1.35	
K	0.008	0.014	0. 20	0.35	
L	0. 039	0. 049	0. 99	1.24	



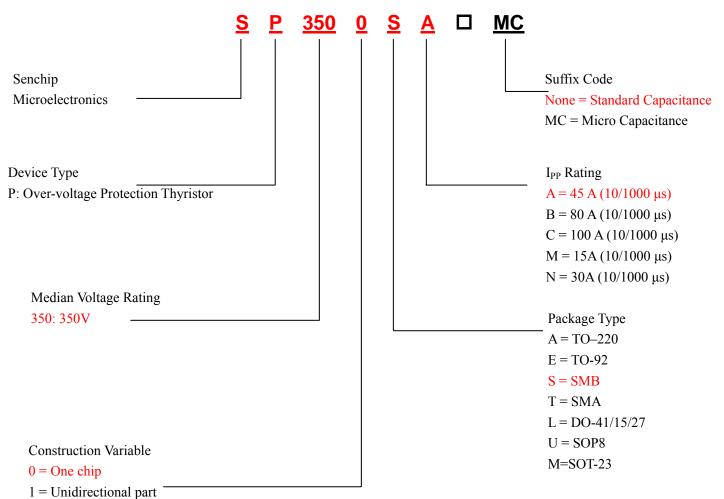
#### **P** Series

#### Over-voltage Protection Thyristor

### SP3500SA

ROHS

#### Description of Part Number

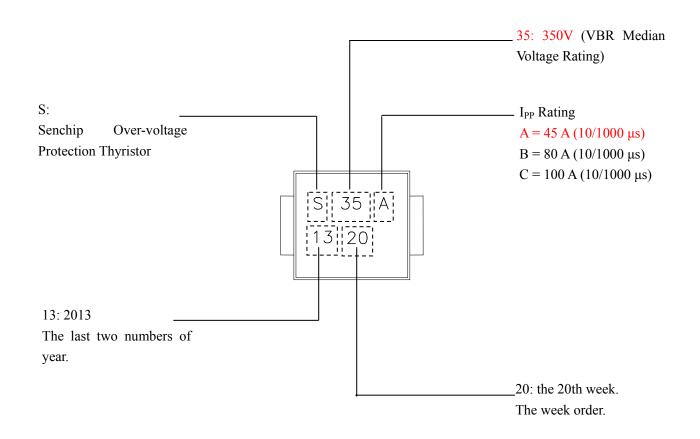


- 2 = Two chips
- 3 = Three chips



## SP3500SA конз

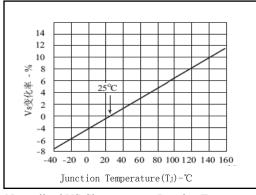
Description of Marking





Senchip	P Series		
Over-voltage Protec	ROHS		
Summary of Packing	Options		
Package Type	Description	Packing Quantity	Industry Standard
DO-214AA SMB			
	Embossed Carrier Reel Pack	2500 PCS	EIA RS-481

#### Thermal Derating Curves



Normalized VS Change versus Junction Temperature

